

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



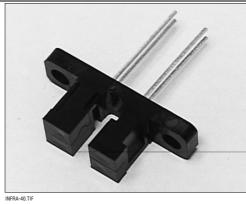




Transmissive Sensor

FEATURES

- · Phototransistor output
- · Accurate position sensing
- · Choice of detector aperture
- 0.125 in.(3.18 mm) slot width
- Dust protective housing



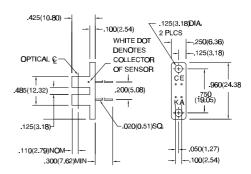
DESCRIPTION

The HOA1879 series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black IR transmissive thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA1879 series employs an IR transmissive housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA1879-011 and -012 have a 0.060 in.(1.52 mm) dia. detector aperture, while the HOA1879-015 has a 0.010 in.(.25 mm) x 0.040 in. (1.02 mm) vertical aperture in front of the detector. This feature is ideal for use in applications where maximum position resolution is desired. The HOA1879 series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is IR transmissive polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM_051.cdr



Transmissive Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I _F =20 mA
Reverse Leakage Current	IR			10	μΑ	V _R =3 V
DETECTOR						
Collector-Emitter Breakdown Voltage	V _(BR) ceo	30			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector Dark Current	ICEO			100	nA	V _{CE} =10 V, I _F =0
COUPLED CHARACTERISTICS						
On-State Collector Current	Ic(on)				mA	V _{CE} =5 V
HOA1879-011		0.4				I _F =20 mA
HOA1879-012		1.8				
HOA1879-015		0.5				
Collector-Emitter Saturation Voltage	Vce(sat)				V	I _F =20 mA
HOA1879-011				0.4		lc=50 μA
HOA1879-012				0.4		Ic=220 μA
HOA1879-015				0.4		Ic=60 μA
Rise And Fall Time	t _r , t _f				μs	Vcc=5 V, lc=1 mA
HOA1879-011, -012, -015	1		15			R _L =1000 Ω

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

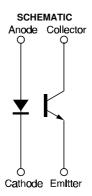
Operating Temperature Range -40°C to 85°C
Storage Temperature Range -40°C to 85°C
Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 100 mW (1)
Reverse Voltage 3 V
Continuous Forward Current 50 mA

DETECTOR
Collector-Emitter Voltage 30 V
Emitter-Collector Voltage 5 V

Power Dissipation 100 mW ⁽¹⁾
Collector DC Current 30 mA

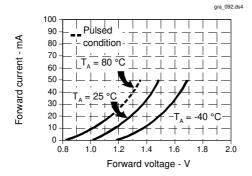


Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

Honeywell

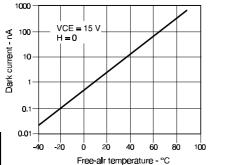
Transmissive Sensor

IRED Forward Bias Characteristics



Non-Saturated Switching Time vs Load Resistance gra_096.ds4 1000 ▤◾▦▦ Response time - µs 100 Photodarlington = | | Phototransistor ŦI#I# 10 100 1000 10000 Load resistance - Ohms

Dark Current vs Fig. 3 Temperature 1000



Collector Current vs Fig. 4 Ambient Temperature gra_095.ds4 Normalized collector current 1.0 0.8 0.4 0.2 0.0 75 -50 Ó 25 50 100 Free-air temperature - °C

All Performance Curves Show Typical Values

Transmissive Sensor